NSN 5962-01-161-3483

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-161-3483

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and 0.3	10 inches
Body Height:	
Between 0.140 inches and 0.1	
Maximum Power Dissipation	Rating:
739.0 milliwatts	
Operating Tempurature Ran	ge:
55.0/+125.0 degrees celsius	
Storage Tempurature Range	
65.0/+150.0 degrees celsius	
End Application:	
Radar system, type an/fps-11	,
Features Provided:	
Hermetically sealed and mono	lithic and high impedance and 3-state output and programmable and bipolar
nclosure Material:	
Ceramic and glass	
nclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
nput Circuit Pattern:	
10 input	
Case Outline Source And De	esignator:
D-2 mil-m-38510	
Terminal Surface Treatment	:
Solder	
Voltage Rating And Type Pe	r Characteristic:
5.5 volts power source	
Time Rating Per Chacteristic	
75.00 nanoseconds propagat	ion delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Jnknown	
Terminal Type And Quantity	:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

